



128K x 8 CMOS EPROM

Features

- Very Fast Read Access Time: (45 200 ns)
- 5V ± 10% Power Supply
- Capable of withstanding >2001V ESD
- · Latch-up Protection up to 200mA
- · Two line control functions to prevent bus contention
- Standard JEDEC Packages
 - 32-pin PLCC
 - 32-pin TSOP (8 x 20mm)
 - 32-pin, 600-mil plastic DIP
 - 32-pin, hermetic LCC
 - -32-pin, 600-mil hermetic DIP
- Available in Commercial, Industrial, and Military Temperature Ranges

Functional Description

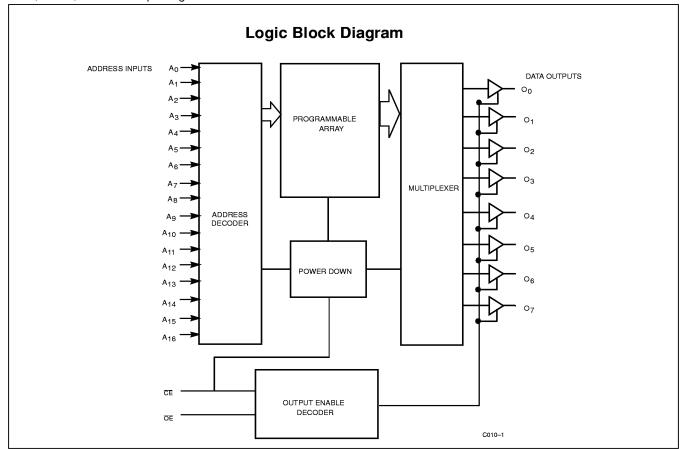
The CY27C010 is a high-performance, 1-Megabit ultraviolet erasable programmable read-only memory (EPROM) organized as 128 Kbytes by 8 bits. It is available in JEDEC-standard, one-time programmable (OTP), 32-pin PDIP, PLCC, and TSOP-I packages. The CY27C010 is also

available in windowed packages (32-pin hermetic DIP and LCC) which allow the device to be erased with UV light for 100% reprogrammability.

The CY27C010 is equipped with a power-down chip enable (CE) input and output enable (OE) to prevent bus contention. When CE is deasserted, the device powers down to a low-power stand-by mode. The OE pin three-states the outputs without putting the device into stand-by mode. While CE offers lower power, OE provides a more rapid transition to and from three-stated outputs.

The memory cells utilize proven EPROM floating-gate technology and byte-wide intelligent programming algorithms. The EPROM cell requires only 12.75V for the supervoltage and low programming current allows for gang programming. The device allows for each memory location to be tested 100%, because each location is written to, erased, and repeatedly exercised prior to encapsulation. Each device is also tested for AC performance to guarantee that the product will meet DC and AC specification limits after customer programming

The CY27C010 is read by asserting both the CE and the OE inputs. The contents of the memory location selected by the address on inputs A16-A0 will appear at the outputs O7-O0.



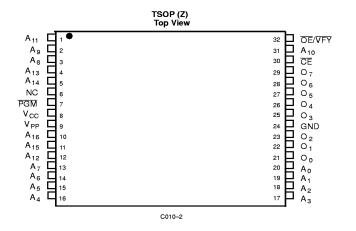
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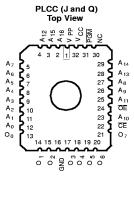
San Jose

CA 95134 408-943-2600 April 1995 Revised: March 14, 1997

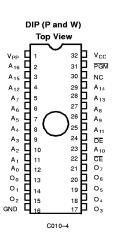


Pin Configurations





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Selection Guide

		-45	-55	-70	-90	-120	-150	-200
Maximum Access Time (ns)		45	55	70	90	120	150	200
CE Access Time (ns)		45	55	70	90	120	150	200
OE Access Time (ns)		20	20	25	30	35	40	60
I _{CC} ^[1] (mA)	Com'l	50	50	50	50	50	50	50
Power Supply Current	Mil	60	60	60	60	60	60	60
I _{SB} ^[2] (mA) Stand-by Current	Com'l(Max)	15	15	15	15	15	15	15
	Mil	25	25	25	25	25	25	25

Maximum Ratings

(Above which the useful life may be imguidelines, not tested.)	paired. For user
Storage Temperature	–65°C to +150°C
Ambient Temperature with Power Applied	–55°C to +125°C
Supply Voltage to Ground Potential	0.5V to +7.0V
DC Voltage Applied to Outputs in High Z State	0.5V to +5.5V
DC Input Voltage	3.0V to +7.0V
Transient Input Voltage	–3.0V for <20 ns
DC Program Voltage	13.0 V
UV Erasure	.7258 W sec/cm ²
Static Discharge Voltage(per MIL-STD-883, Method 3015)	>2001V
Latch-Up Current	>200 mA

Operating Range

Range	Ambient Temperature	V _{cc}
Commercial	0°C to +70°C	5V ± 10%
Industrial ^[3]	-40°C to +85°C	5V ± 10%
Military ^[4]	-55°C to +125°C	5V ± 10%

Notes:

- 1. $V_{CC} = Max.$, $I_{OUT} = 0$ mA, f=5 MHz.
- 2. $V_{CC} = Max., \overline{CE} = V_{IH}.$
- Contact a Cypress representative for industrial temperature range specification.
- 4. TA is the "instant on" case temperature.



DC Electrical Characteristics Over the Operating Range^[5, 6]

Parameter	Description	Test Conditions		Min.	Max.	Unit
V _{OH}	Output HIGH Voltage	$V_{CC} = Min., I_{OH} = -400\mu A$		2.4		V
V _{OL}	Output LOW Voltage	V _{CC} = Min., I _{OL} = 2.1mA			0.45	V
V _{IH}	Input HIGH Level	Guaranteed Input Logical HIGH Voltage for All Inputs		2.0	V _{CC} +0.5	V
V _{IL}	Input LOW Level	Guaranteed Input Logical LOW Voltage for All Inputs			0.8	V
I _{LI}	Input Leakage Current	$GND \le V_{IN} \le V_{CC}$		-10	+10	μΑ
I _{LO}	Output Leakage Current	$\begin{aligned} & \text{GND} \leq \text{V}_{OUT} \leq \text{V}_{CC}, \\ & \text{Output Disable} \end{aligned}$		-10	+10	μΑ
I _{CC}	Power Supply Current	V _{CC} =Max., I _{OUT} =0 mA,	Com'l		50	mA
		f=5 MHz	Mil		60	mA
I _{SB}	Stand-By Current	V _{CC} =Max., CE = V _{IH}	Com'l (max)		15	mA
		GE = VIH	Mil		25	mA

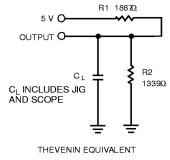
Capacitance^[7]

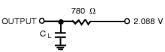
Parameter	Description	Test Conditions	Max	Unit
C _{IN}	Input Capacitance	$T_A = 25^{\circ}C, f = 1 \text{ MHz},$	10	pF
C _{OUT}	Output Capacitance	V _{CC} = 5.0V	10	pF

Notes:

- See the last page of this specification for Group A subgroup testing information. See Introduction to CMOS NVMs in this Data Book for general information on testing. This parameter is sampled only and is not 100% tested.

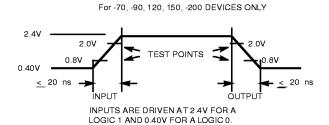
AC Test Loads and Waveforms

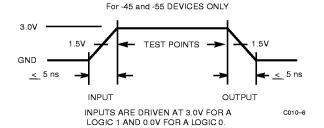




Notes: $C_L = 30pF$ for -45 and -55 devices C_L = 100pF for -70, -90, -120, -150, and -200 devices C_L = 5pF for t_{DF}

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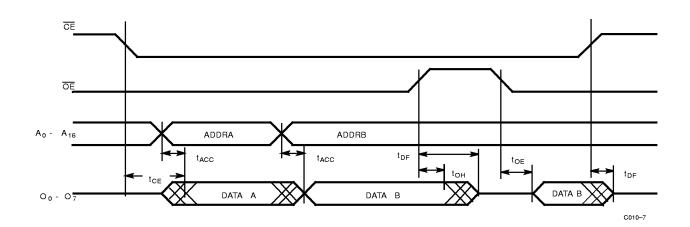


Switching Characteristics Over the Operating Range

		_	45	-:	55		70	-	90	-1	20	-1	50	-2	200	
Parame- ter	Description	Min	Max	Unit												
t _{ACC}	Address to Output Valid		45		55		70		90		120		150		200	ns
t _{OE}	OE Active to Output Valid		20		20		20		25		25		30		30	ns
t _{DF} ^[8]	OE or CE Inactive to High Z, which- ever occurs first		20		25		25		30		35		40		60	ns
t _{CE}	CE Active to Output Valid		45		55		70		90		120		150		200	ns
t _{OH}	Output Data Hold	0		0		0		0		0		0		0		ns

Note:

Switching Waveform



Erasure Characteristics

Wavelengths of light less than 4000 Angstroms begin to erase the CY27C010 in the windowed package. For this reason, an opaque label should be placed over the window if the EPROM is exposed to sunlight or fluorescent lighting for extended periods of time.

The recommended dose of ultraviolet light for erasure is a wavelength of 2537 Angstroms for a minimum dose (UV intensity multiplied by exposure time) of 15 Wsec/cm2. For an ultraviolet lamp with a 12 mW/cm² power rating, the exposure time would be approximately 15 minutes. The CY27C010

needs to be within 1 inch of the lamp during erasure. Permanent damage may result if the EPROM is exposed to high-intensity UV light for an extended period of time. 7258 Wsec/cm² is the recommended maximum dosage.

Programming Modes

Programming support is available from Cypress as well as from a number of third-party software vendors. For detailed programming information, including a listing of software packages, please see the PROM Programming Information located at the end of this section. Programming algorithms can be obtained from any Cypress representative.

^{8.} This parameter is sampled only and is not 100% tested.



Table 1. Programming Electrical Characteristics

Parameter	Description	Min.	Max.	Unit
V _{PP}	Programming Power Supply	12.5	13	V
I _{PP}	Programming Supply Current		50	mA
V _{IHP}	Programming Input Voltage HIGH	3.0	V _{CC}	V
V _{ILP}	Programming Input Voltage LOW	-0.5	0.4	V
V _{CCP}	Programming V _{CC}	6.0	6.5	٧

Table 2. Mode Selection

		Pin Function ^[9]								
Mode	CE	ŌĒ	PGM	V _{PP}	A ₀	A ₉	Outputs			
Read	V _{IL}	V _{IL}	Х	Х	A ₀	A ₉	Dout			
Output Disable	Х	V _{IH}	Х	Х	Х	Х	High Z			
Stand-by(TTL)	V _{IH}	Х	Х	Х	Х	Х	High Z			
Program	V _{ILP}	V _{IHP}	V _{ILP}	V _{PP}	A ₀	A ₉	Din			
Program Verify	V _{ILP}	V _{ILP}	V _{IHP}	V _{PP}	A ₀	A ₉	Dout			
Program Inhibit	V _{IHP}	Х	Х	V _{PP}	Х	Х	High Z			
Signature Read (MFG) ^[11]	V _{IL}	V _{IL}	Х	V _{IH}	V _{IL}	V _{HV} [10]	34H			
Signature Read (DEV)[11]	V _{IL}	V _{IL}	Х	V _{IH}	V _{IH}	V _{HV} [10]	1DH			

Notes:

- 9. X can be V_{IL} or V_{IH}
- 10. V_{HV}=12V±0.5V
- 11. A_1 A_8 and A_{10} A_{16} = V_{IL}



Ordering Information $^{[12]}$

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
45	CY27C010-45JC	J65	32-Lead Plastic Leaded Chip Carrier	Commercial
	CY27C010-45PC	P15	32-Lead (600-Mil) Molded DIP	
	CY27C010-45WC	W20	32-Lead (600-Mil) Windowed CerDIP	
	CY27C010-45ZC	Z32	32-Lead Thin Small Outline Package	
	CY27C010-45QMB	Q55	32-Pin Windowed Rectangular Leadless Chip Carrier	Military
	CY27C010-45WMB	W20	32-Lead (600-Mil) Windowed CerDIP	
55	CY27C010-55JC	J65	32-Lead Plastic Leaded Chip Carrier	Commercial
	CY27C010-55PC	P15	32-Lead (600-Mil) Molded DIP	
	CY27C010-55WC	W20	32-Lead (600-Mil) Windowed CerDIP	
	CY27C010-55ZC	Z32	32-Lead Thin Small Outline Package	
	CY27C010-55QMB	Q55	32-Pin Windowed Rectangular Leadless Chip Carrier	Military
	CY27C010-55WMB	W20	32-Lead (600-Mil) Windowed CerDIP	
70	CY27C010-70JC	J65	J65 32-Lead Plastic Leaded Chip Carrier	
	CY27C010-70PC	P15	32-Lead (600-Mil) Molded DIP	-
	CY27C010-70WC	W20	32-Lead (600-Mil) Windowed CerDIP	
	CY27C010-70ZC	Z32	32-Lead Thin Small Outline Package	-
	CY27C010-70QMB	Q55	32-Pin Windowed Rectangular Leadless Chip Carrier	Military
	CY27C010-70WMB	W20	32-Lead (600-Mil) Windowed CerDIP	-
90	CY27C010-90JC	J65	32-Lead Plastic Leaded Chip Carrier	Commercial
	CY27C010-90PC	P19	32-Lead (600-Mil) Molded DIP	-
	CY27C010-90WC	W20	32-Lead (600-Mil) Windowed CerDIP	-
	CY27C010-90ZC	Z32	32-Lead Thin Small Outline Package	-
	CY27C010-90QMB	Q55	32-Pin Windowed Rectangular Leadless Chip Carrier	Military
	CY27C010-90WMB	W20	32-Lead (600-Mil) Windowed CerDIP	
120	CY27C010-120JC	J65	32-Lead Plastic Leaded Chip Carrier	Commercial
	CY27C010-120PC	P19	32-Lead (600-Mil) Molded DIP	1
	CY27C010-120WC	W20	32-Lead (600-Mil) Windowed CerDIP	1
	CY27C010-120ZC	Z32	32-Lead Thin Small Outline Package	1
	CY27C010-120QMB	Q55	32-Pin Windowed Rectangular Leadless Chip Carrier	Military
	CY27C010-120WMB	W20	32-Lead (600-Mil) Windowed CerDIP	1
		1	1	



Ordering Information^[12] (continued)

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
150	CY27C010-150JC	J65	32-Lead Plastic Leaded Chip Carrier	Commercial
	CY27C010-150PC	P19	32-Lead (600-Mil) Molded DIP	
	CY27C010-150WC	W20	32-Lead (600-Mil) Windowed CerDIP	
	CY27C010-150ZC	Z32	32-Lead Thin Small Outline Package	
	CY27C010-150QMB	Q55	32-Pin Windowed Rectangular Leadless Chip Carrier	Military
	CY27C010-150WMB	W20	32-Lead (600-Mil) Windowed CerDIP	
200	CY27C010-200JC	J65	32-Lead Plastic Leaded Chip Carrier	Commercial
	CY27C010-200PC	P19	32-Lead (600-Mil) Molded DIP	
	CY27C010-200WC	W20	32-Lead (600-Mil) Windowed CerDIP	
	CY27C010-200ZC	Z32	32-Lead Thin Small Outline Package	
	CY27C010-200QMB	Q55	32-Pin Windowed Rectangular Leadless Chip Carrier	Military
	CY27C010-200WMB	W20	32-Lead (600-Mil) Windowed CerDIP	

Note

MILITARY SPECIFICATIONS Group A Subgroup Testing

DC Characteristics

Parameter	Subgroups
V _{OH}	1, 2, 3
V _{OL}	1, 2, 3
V _{IH}	1, 2, 3
V _{IL}	1, 2, 3
ILI	1, 2, 3
I _{LO}	1, 2, 3
Icc	1, 2, 3
I _{SB}	1, 2, 3

Switching Characteristics

Parameter	Subgroups
t _{ACC}	7, 8, 9, 10, 11
t _{OE}	7, 8, 9, 10, 11
t _{CE}	7, 8, 9, 10, 11

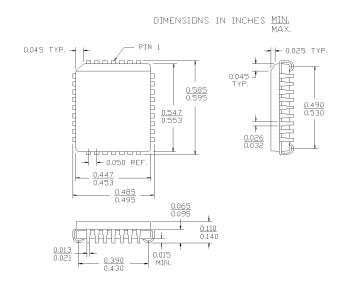
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^{12.} Contact a Cypress sales representative for industrial temperature offerings.

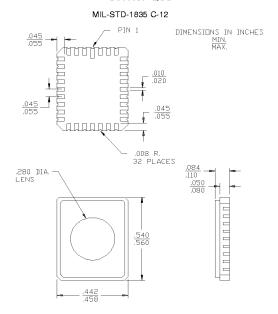


Package Diagrams

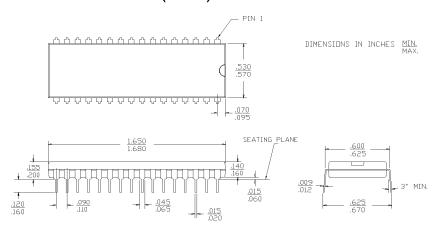
32-Lead Pastic Leaded Chip Carrier J65



32-Pin Windowed Rectangular Leadless Chjp Carrier Q55



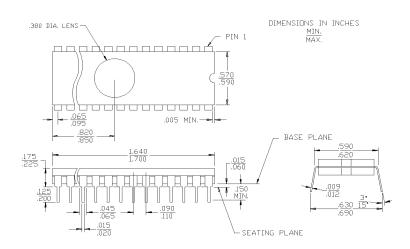
32-Lead (600-Mil) Molded DIP P19



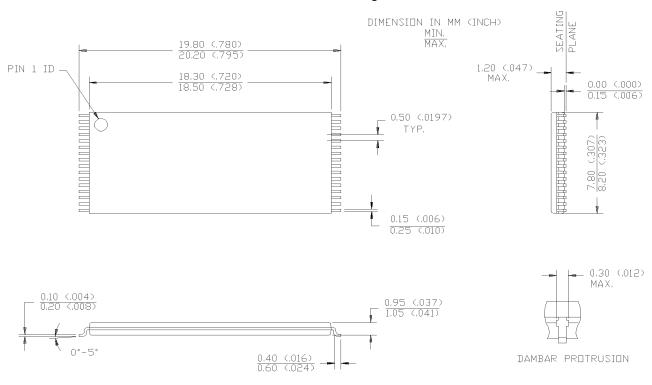


Package Diagrams (continued)

32-Lead (600-Mil) Windowed CerDIP W20



32-Lead Thin Small Outline Package Z32



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